

Direct measurements of spin-dependent and coherent effects in conductance of a ferromagnet/superconductor system

Yu. N. Chiang, O. G. Shevchenko, and R. N. Kolenov
*B. I. Verkin Institute for Low Temperature Physics and Engineering,
 National Academy of Sciences of Ukraine
 47 Lenin Ave, Kharkov 61103, Ukraine
 E-mail: chiang@ilt.kharkov.ua*

In the systems ferromagnet/superconductor ([Fe, Ni]/In), the temperature dependent transport has been investigated within the temperature range including superconducting transition temperature for Indium. It has been found that when Indium becomes superconducting, the system resistance acquires two positive additions. The first, numerically equal to the resistance of a ferromagnet part, of order of a spin-polarized region in length, corresponds to the manifestation of "spin accumulation" effect. The second agrees in magnitude with an interference reduction in the ferromagnet conductance over the coherence length for singlet "Andreev pairs" which is established by the exchange field in the ferromagnet. From the experimental data, the degree of current spin polarization, the coherence length in the exchange field, and the lower limit of spin-relaxation length in Fe and Ni have been estimated.

The possibility for spin characteristics of conduction electrons to reveal in metal transport is widely studied both theoretically and experimentally which fact indicates that the problems in description and identification of experimental data in this field is still far from complete. For example, on measuring transport properties of mesoscopic heterosystems ferromagnet/superconductor (F/S), an intriguing suggestion has been made [1–3] that in ferromagnets, a long-range proximity effect for Andreev excitations with the energies $\varepsilon \sim T < \Delta$ (Δ is the order parameter) may exist over the length scale exceeding conventional estimates. Later analysis [4] of the experiments pointed to some special features concerning, in particular, the necessity to properly account for the current distribution in planar mesoscopic interfaces. Besides, the properties of such interfaces in the form of sandwiches are closely related to the particular technologies of their preparing. An uncertainty is thus introduced into the values of the transmission coefficient and potential barrier height at the interfaces, even for the nanostructures prepared by the technologies of similar type [5]. Moreover, since the potential difference is usually measured with the interface included (see, for example, [2, 3]), this circumstance may seriously interfere with interpreting the effects inherent for a ferromagnet.

As an illustration, the comparative temperature dependences of the potential difference normalized to the current, U/I , are plotted in Fig. 1 for the N/S system normal-metal/superconductor (Cu/Sn) in cases when the probes do or do not enclose the interface [6]. Curve 1 measured beyond the interface accounts for the fundamental proposition in theory [7, 8] that at inserting Andreev reflection, the interference of electrons (e) and Andreev holes (h) along the e - h coherence length, ξ_T , measured from N/S interface leads to the increase in elastic scattering cross-section, i. e. to decreasing (not increasing, as in case the scattering is not considered [9–11]) the conductance of a normal metal. At the same time, total potential difference in the whole circuit, with the interface included (most popular experimental arrangement), after the superconducting transition may bear the opposite character, not related to the effects in the conductivity of a normal metal (curve 2, see also [2]). It is the behavior of this kind that is often treated as possible manifestation of the long-range proximity effect in the conductance of a non-superconducting section of the system.

With the aforementioned measurement configuration, the conclusion on the nature of the processes may also be inadequate when the geometry of the planar interface is such that a superconductor, as a part of the potential lead, overlaps a noticeable area δA of the non-superconducting film investigated, and, in doing so, shunts it when turning into the S-state. With comparatively small thicknesses of

such a layer is evidenced by the pronounced "non-Sharvin" resistance of the barriers in mesoscopic interfaces), the inevitable drop in the system resistance due to the shunting is of order of $\delta R/R \approx \delta A/A$ which value is often observed [2, 3]. In experiments measuring the "nonlocal" resistance of the F/S systems [12], the shunting effect may be revealed as well at the interfaces removed not too far, due to the current spreading into the branches. The distribution of the electric potential in the branches which size in mesoscopic samples is comparable to that of the main circuit, is a direct evidence that the above situation is real. As known, the distribution obeys the Laplace equation (see, for example, [13]). The solution for the current near the interface in the branch, L in length and of width and thickness identical to those of the main circuit, is the following expression: $j(x) \approx j(x_0)(1/4\sqrt{\pi})(x/x_0) \exp[-(x-x_0)/x_0]$. Here, x_0 is the beginning of the branch measured from the current injector; $x_0 \leq x \leq L$. In mesoscopic samples, the effect should be rather noticeable. Therefore, in the heterosystems consisted of a ferromagnet and a superconductor, a few competitive mechanisms may appear after switching into the F/S regime. The first gives rise to the increase in the potential difference measured within the range of the coherence length of the non-superconducting part of the system, due to Andreev interference. The second diminishes that difference due to the shunting effect (the behavior of that type was observed in Ref. [12]). The last is the effect at the F/S interface itself. It is associated with the mismatch between spin-polarized current in a ferromagnet and spinless current of the Cooper pairs in a singlet superconductor and is known as spin accumulation [15, 16].

Below we present experimental investigations of transport properties of the crystalline heterostructures Fe/In and Ni/In, with F/S interfaces prepared specifically, to obtain high-transparency barriers and, as a result, to minimize the difference between various F/S interfaces. We have studied the conductance of the ferromagnet metals with different electron scattering lengths adjacent to a superconductor, the phenomena at the F/S interface under Andreev reflection and current polarization, and the shunting effect in the vicinity of superconducting transition. We use four-terminal technique of various configurations and different relations between the dimensions of the ferromagnet conductors and F/S interfaces.

Our main results are as follows: i) We have observed the *increase* in the resistance of F/S interfaces Fe/In and Ni/In as an evidence for spin accumulation resulted from the peculiarities of Andreev reflection at the F/S interface under current polarization in a ferromagnet; ii) we have first revealed the interference contribution from Andreev excitations into the conductance of a ferromagnet (Ni) within the limits of a coherence length typical of ferromagnets.

The samples were cut by the spark-erosion method from two bulk ferromagnetic metals which differ greatly in purity, polycrystalline Fe with Residual Resistance Ratio $RRR \approx 3$ and monocrystalline Ni with $RRR \approx 200$. Mean free paths, l_{el} , at helium temperatures were estimated to be approximately $0.01 \mu\text{m}$ (the value most typical of known nanostructures) and $2 \mu\text{m}$ for Fe and Ni, respectively.

Fig. 2 presents a schematic view of the sample configurations. The working area of the samples, with F/S interfaces at the points a and b is marked by dashed lines. When Indium bridge closes the points a and b the working area gains the geometry of an enclosed "Andreev interferometer" which allows us to study phase-sensitive effects as well (will be presented elsewhere).

The superconducting In bridge ab was soldered to the prepared in advance [Fe, Ni]/In interfaces. Point-like interfaces were fabricated by mechanically destroying a superficial layer of the ferromagnet metal and simultaneously coating it with melted Indium of high purity ($RRR \approx 4 \cdot 10^4$). Indium was applied onto a tip of an iron solderer sharpened to the diameter $50 \div 100 \mu\text{m}$. The measured contact resistance of such interfaces does not exceed $1.5 \cdot 10^{-4} \Omega$. To minimize the shunting effect, the ratio between a contact size and sample width was made down to approximately 0.1. The shunting effect was studied separately on the Ni sample with purpose designed wide interfaces, see Inset b to Fig. 4.

The dimensions of the working area elements were as follows. For Fe sample: width of the ferromagnetic conductors $W_{ac,bd} \approx 1.5 \text{ mm}$; $W_{cd} \approx 0.5 \text{ mm}$; their length $L_{ac,bd} \approx 0.5 \text{ mm}$; $L_{cd} \approx 0.3 \text{ mm}$; thickness $t \approx 0.25 \text{ mm}$. For Ni sample: $W_{ac,bd} \approx 0.5 \text{ mm}$; $W_{cd} \approx 0.7 \text{ mm}$; $L_{ac,bd} \approx 0.5 \text{ mm}$; $L_{cd} \approx 0.4 \text{ mm}$ and $t \approx 0.1 \text{ mm}$. The measuring configuration in each specific case is shown in the Insets to the Figures.

After curves 1 (Fig. 3, 5) were taken, the resistances of the working area elements, $R_{ac}(T)$, $R_{bd}(T)$, $R_{cd}(T)$, were independently measured by four-terminal technique. In this case,

sample or the ends of the opened Indium bridge *ab* (see Fig. 2) were used as potential leads, the current flow configuration remaining fixed.

We achieved a resistance resolution better than 10^{-4} due to temperature and current ($0.1 \div 1$ A) stabilization and using the voltmeter based on a superconducting modulator accurate within $\delta U \approx 10^{-11}$ V [15] for measuring potential difference.

Curve 1 in Fig. 3 depicts the temperature dependence of the potential difference V_1 and V_2 at the ends of the *cab* part, $U_{cb}(T) = |V_1 - V_2|(T)$, normalized to the current in the branch *cabd* formed by two Fe conductors *ac* and *bd*, two Fe/In interfaces, and In bridge *ab* (see Inset). The current was determined from the Kirchhoff's laws $I = I_{cabd}(1 + I_{cd}/I_{cabd})$; $I_{cd}/I_{cabd} = R_{cabd}/R_{cd}$:

$$I_{cabd}(T) = \frac{IR_{cd} - U_{ab}^{\text{In}} - 2(U_{\text{interface}} + \delta U_{ac})}{R_{\Sigma}} \Big|_T; \quad (1)$$

$$R_{\Sigma}|_T = [R_{ac} + R_{bd} + R_{cd}]_T; \quad [U_{\text{interface}} + \delta U_{ac}]_T = [U_{cb} - (U_{ab}^{\text{In}} + U_{ac})]_T.$$

Here, U_{ab}^{In} is the voltage drop measured independently at In bridge, $U_{\text{interface}}$ the potential difference at the interface, R_{Σ} the total resistance of the ferromagnetic part of the contour *acdb*, and $\delta U_{ac}(T)$ a possible addition into the voltage $U_{ac}(T)$ across the ferromagnet branch *ac* which was measured in the configuration excluding the potential difference at the F/S interface (see above).

As in case with non-magnetic metal in the N/S system Cu/Sn (Fig. 1, curve 2), the temperature-dependent resistance of the F/S system Fe/In (Fig. 3, curve 1) alone does not give an indication of true resistive contributions from the individual parts that form the F/S system. To separate those contributions, we should compare curve 1 with the temperature behavior of the resistance of the same system at the temperatures below superconducting transition temperature for Indium, $T_c^{\text{In}} = 3.41$ K (curve 2) where the resistance of In bridge turns to zero (see Inset *b* to Fig. 3).

Comparing the curves in Fig. 3, $U_{cb}/I_{cabd}(T)$ (curve 1) and $R_{ac}(T) \equiv [U_{ac}/I_{cabd}]_T$ (curve 2) at the temperatures $T \leq T_c^{\text{In}}$, we conclude that when the interface changes from the F/N to the F/S state, the resistance of the whole system Fe+F/S interface increases as opposed to that of the Fe part *ac*. Since the latter does not change significantly (except a hardly visible reduction due to the shunting effect, see lower panel in Fig. 3) the rise in the former may be attributed to the effect at the F/S interface. The temperature dependence of the Fe/In interface resistance, $R_{\text{interface}}$, obtained by subtracting the dependencies $R_{ac}(T)$ and $U_{ab}^{\text{In}}/I_{cabd}$ from curve 1 is shown as curve 2 in Fig. 6.

Fig. 4 displays the resistance R_{Σ} of the same part *acdb* of the system Ni/In measured in the presence of wide (curve 1) or point-like (curve 2) F/S interfaces. In both cases, with the measuring configurations shown (see corresponding Insets), the interface resistance is excluded as being a part of potential leads. It can be seen that at $T \leq T_c^{\text{In}}$, after Andreev reflection turns on, the resistance R_{Σ} increases abruptly by $\approx 1 \cdot 10^{-8} \Omega$ in case of two point contacts ($\delta R/R \approx 0.035\%$) or by $\approx 7 \cdot 10^{-7} \Omega$ in case of two wide interfaces ($\delta R/R \approx 2.5\%$).

According to [6–8] the interference contribution from Andreev excitations scattered at the impurities within a metal layer, of order of coherence length ξ for Andreev hybrid in thickness, which is measured at a distance L from the N/S interface, provided $l_{el} \geq \xi$, d (d is the characteristic size of the interface), is given by

$$\frac{\delta R}{R} \Big|_{\text{int}} = \frac{\xi}{L} \bar{\tau}. \quad (2)$$

Here, $\bar{\tau}$ is the effective probability for each excitation from an Andreev pair to scatter elastically in the layer ξ , regardless of the number of the pairs, i. e., of the probability of Andreev reflection. The number of Andreev hybrids is established by the transmission coefficient of an N/S interface and by the selection rules. The voltage at the interfaces in our experiments did not exceed 0.15 meV for Fe/In and 3 μ eV for Ni/In, thus, we can entirely neglect the potential difference at the barrier. Therefore, it follows from Eq. (2) that, in principle, the resistance of the metal layer, $L = \xi$ in thickness, may double under Andreev reflection if $\bar{\tau} = 1$.

Consider now ferromagnet metals. On quasiclassical notion, the coherence of the Andreev pair of excitations in an impure metal is considered to be destructed when the displacement of their trajectories relative to each other reaches the value exceeding the size of an impurity (of order of the de Broglie

place in a ferromagnet exchange field H_{exch} due to the Larmour curving of e and h trajectories, is of order of the Larmour radius R_L [19] and is given by

$$\xi_m \sim \frac{R_L}{2\pi} = \frac{\hbar v_F}{k_B T_{exch}}, \quad l_{el} \geq \xi_m \quad (3)$$

($k_B T_{exch} \equiv \mu H_{exch}$, μ is the Bohr magneton). ξ_m is fixed and corresponds to a maximum possible coherence length in a ferromagnet with elastic scattering length $l_{el} \geq \xi_m$. For $l_{el} < \xi_m$ and, hence, low diffusion coefficient D , the coherence length is additionally restricted to:

$$\xi_{exch}^D \sim \sqrt{(1/3)l_{el}\xi_m} < \xi_m, \quad l_{el} < \xi_m. \quad (4)$$

For Fe, the Curie temperature T_{exch} is approximately 900 K, and $\xi_m \approx 0.05 \mu\text{m}$. According to the estimates, ξ_{exch}^D for our Fe samples, with $l_{el} \leq 0.01 \mu\text{m}$, is too small in order that the interference contribution (2) can be detected. In contrast, for Ni, with $T_{exch} \simeq 600$ K and $l_{el} \sim 1 \mu\text{m}$, the equation (3) is valid, and theoretical estimate yields $\xi_m \sim 0.1 \mu\text{m}$. The coherence length in our Ni samples is independently evaluated at $\xi \approx 0.1 \mu\text{m}$. We used Eq. (2) and the experimental data for $\delta R/R$ for the point and wide interfaces Ni/In. For the wide interface, it was accounted that the number of Andreev channels should be proportional to the F/S contact area. Therefore, such an unexpected at first glance manifestation of the coherent effect in a ferromagnet we observed does not fall outside the scope of *conventional* concepts of the coherence length scale for Andreev excitations in ferromagnetic metals and has nothing to do with the long-range proximity effect.

The fall on curve 1, Fig. 4, at $T \approx T_c^{\text{In}}$ testifies that when a superconducting potential lead overlaps a part of a normal conductor, a shunting effect appears due to spreading the current into a superconductor. The effect may dominate any other effects in conductance of a metal investigated under the geometry of a three-layered sandwich (in planar nanostructures) where the resistance of the intermediate layer is, as a rule, lower than that of a normal metal but higher than that of a superconductor. That is why we used the technology of preparing the interfaces described above, which allowed us to get the geometry approaching two-layered one. In this case, the shunting effect, though visible, is comparable in value to the effect of interference decrease in conductance of the metal investigated and is at most twice as much as the latter (see curve 1, Fig. 4).

Fig. 5 displays the temperature-dependent potential differences for Ni/In sample with wide interfaces normalized to the current I_{cabd} (see Eq. (1)). Curve 1, $U_{ab}^1(T) = |V_{11} - V_{12}|(T)$, was taken immediately at the Indium bridge while curve 2, $U_{ab}^2 = |V_{21} - V_{22}|(T)$, was taken at the Ni leads, see Inset to Fig. 5. In both configurations, the effects beyond the interfaces are eliminated and the comparison between the two curves allows us to draw a conclusion of the effects proper to the interface, and their temperature behavior.

In Fig. 6, curve 1, we present the resistance vs temperature of wide F/S interfaces in the Ni/In sample (at points a and b) as a difference between curves 1 and 2, Fig. 5, together with that of Fe/In point interface (curve 2, see above). As seen, the resistive behavior of both wide (Ni/In) and point (Fe/In) interfaces is qualitatively similar, irrespective of the interface geometry. At $T > T_c^{\text{In}}$, the interface resistance varies with temperature as a result of known change in electron-phonon mean free paths of the metals next to the interface. When Indium goes to the superconducting state the current component perpendicular to the plane of an interface disappears. Entering into the superconducting bridge ab the current is thus driven to the edges of the interface. "Interface resistance" at the minimum of curves 1, 2 can be treated as a certain minimal value reached at $T = T_c^{\text{In}}$. It is this value that should serve as an origin point when calculating any resistive contributions into the interface resistance if only those may appear when Andreev reflection turns on. As seen from Fig. 6, these contributions, $\delta R_{F/S}/R_{F/N}$, are positive for both metals and reach the following values: about 40% for Ni/In (curve 1) and about 20% for Fe/In (curve 2).

The above findings we consider as a direct confirmation of spin accumulation at the interfaces Fe/In and Ni/In. It is clearly demonstrated especially in case of Ni/In interface where the contribution from the transport effects in a ferromagnetic branch beyond the interface was almost entirely eliminated. It would appear reasonable that the value of the resistive jump at the Ni/In interface is entirely determined by the contribution from small disequilibrium regions close to the superconducting potential

the Ni/In interface does not exceed the spin relaxation length, λ_s , in nickel investigated.

In fact, the value for $\delta R_{F/S}/R_{F/N}$ for the sample Fe/In was obtained in the configuration included the resistance of a *long* ferromagnetic branch, in any case, of no less than a spin-relaxation length in size. It appeared to be approximately of the same order of magnitude as that for the sample Ni/In. Therefore, we may conclude that in both our samples, the spatial scale of the spin-relaxation length λ_s should be of the same order of magnitude. As known from theory [15, 16, 4], the change in the resistance of the F/S interface due to spin-accumulation effect, $\delta R_{F/S}$, is comparable to the resistance of a ferromagnet part of the length equal to the spin-flip length:

$$\delta R_{F/S} = \frac{\lambda_s}{\sigma A} f(P), \quad (5)$$

$$f(P) = \frac{P^2}{1 - P^2}; \quad P = (\sigma_{\uparrow} - \sigma_{\downarrow})/\sigma; \quad \sigma = \sigma_{\uparrow} + \sigma_{\downarrow}.$$

Here, P is the degree of spin polarization; σ , σ_{\uparrow} , σ_{\downarrow} , and A the total, spin-dependent conductivities, and the cross-section of a ferromagnet, respectively. Using Eq. (5) and geometric parameters for our samples and taking into account that $P^{Fe} \approx P^{Ni}$ [18] we find

$$\frac{\lambda_s^{Fe}}{\lambda_s^{Ni}} = \frac{\delta R_{Fe/S}}{\delta R_{Ni/S}} \cdot \frac{l_{el}^{Fe}}{l_{el}^{Ni}} \cdot \frac{A^{Fe}}{A^{Ni}} \approx 2. \quad (6)$$

This result confirms that the spatial scales of the spin-flip length, λ_s^{Fe} and λ_s^{Ni} , in our samples are comparable. Therefore, the size of the region which determines the value of the spin-accumulation effect observed is no more than the spin-relaxation length in each metal. In this case, according to Eq. (5), it is the values of λ_s for Fe/In and λ_s^* for Ni/In that we should use as the length of the conductors to the resistance $R_{F/N}$ of which we compare the values $\delta R_{F/S}$ obtained in the experiment. It allows us to estimate independently the degree of conductance spin polarization for Fe and Ni from our experimental data:

$$P = \sqrt{(\delta R_{F/S}/R_{F/N})/(1 + \delta R_{F/S}/R_{F/N})}, \quad (7)$$

whence it follows that $P^{Fe} \approx 45\%$ and $P^{Ni} \approx 50\%$. The values coincide practically with those obtained from other experiments [20]. We can roughly estimate the spin-relaxation length in the metals investigated if by A in Eq. (5) is meant the cross-section of the contour through which the current is injected into the superconducting bridge, i. e., the production of the interface contour length by the width of the Meissner layer. This yields $\lambda_s^{Fe} \sim 900$ Å and $\lambda_s^{Ni} > 500$ Å.

In conclusion, we have investigated spin-dependent conductance of the macroscopic heterosystems ferromagnet (Fe, Ni) / superconductor (In) and obtained further evidence for the spin accumulation to exist at the F/S interfaces. The effect results from the peculiarities of Andreev reflection under current polarization in a ferromagnet. Previously, the experiments on the system Ni/Al of submicron size [21] have led to the similar conclusion. In addition, we have first proved that the coherent effects in the conductance of a ferromagnet (nickel) contacted to a superconductor can be observed within the limits of a coherence length for Andreev excitations *typical* of a ferromagnet, provided the ferromagnet is pure enough. Our experiments verify that the coherence length in a pure ferromagnet may appear to be comparable to that length in a non-magnetic metal with shorter elastic scattering length of electrons. Our results do not confirm the possible existence of the long-range proximity effect in conventional ferromagnets.

References

- [1] S. Guéron, H. Pothier, N. O. Birge, D. Esteve, and M. H. Devoret, Phys. Rev. Lett. **77**, 3025 (1996).
- [2] V.T. Petrashov, I. A. Sosnin, I. Cox, A. Parsons, and C. Troadec, Phys. Rev. Lett. **83**, 3281 (1999).

- (2003).
- [4] W. Belzig, A. Brataas, Yu. V. Nazarov, and G. E. W. Bauer, Phys. Rev. B **62**, 9726 (2000).
 - [5] B. Y. Jin, J. B. Ketterson, Adv. Phys. **38**, 189 (1989).
 - [6] Yu. N. Chiang and O. G. Shevchenko, JETP **86**, 582 (1998); Low Temp. Phys. **25**, 314 (1999).
 - [7] J. Herath, D. Rainer, Physica C **161**, 209 (1989).
 - [8] A. M. Kadigrobov, Low Temp. Phys. **19**, 671 (1993).
 - [9] G. E. Blonder, M. Tinkham, and T. M. Klapwijk, Phys. Rev. B **25**, 4515 (1982).
 - [10] M. J. M. De Jong and C. W. J. Beenakker, Phys. Rev. Lett. **74**, 1657 (1995).
 - [11] C. J. Lambert and R. Raimondi, J. Phys.: Condensed Matter **10**, 901 (1998).
 - [12] O. D. Beckmann, H. B. Weber, and H. v. Lohneysen, Phys. Rev. Lett. **93**, 197003 (2004).
 - [13] J. A. Delaney and A. B. Pippard, Repts. Progr. Phys. **35**, 677 (1972).
 - [14] H. Jeffreys and B. Swirles, *Methods of Mathematical Physics* (Cambridge: Univ. Press, 1966).
 - [15] V. I. Fal'ko, A. F. Volkov, C. J. Lambert, JETP Lett. **69**, 532 (1999); cond-mat/9901057.
 - [16] F. J. Gedema, B. J. van Wees, B. H. Hoving, A. T. Filip, and T. M. Klapwijk, Phys. Rev. B **60**, 16549 (1999); cond-mat/9901323.
 - [17] Yu. N. Chiang, Prib. Tekh. Eksp. **1**, 202 (1981).
 - [18] B. J. van Wees, P. de Vries, P. Magnic, and T. M. Klapwijk, Phys. Rev. Lett. **69**, 510 (1992).
 - [19] Yu. N. Chiang, JETP Lett. **71**, 334 (2000).
 - [20] R. J. Soulen Jr. *et al.*, Science **282**, 85 (1998).
 - [21] J. Aumentado and V. Chandrasekhar, Phys. Rev. B **64**, 054505 (2001).

Fig. 1. Temperature dependence of the resistance of the system normal-metal /superconductor (Cu/Sn) in the measuring configurations beyond the interface (curve 1) and including the interface (curve 2) [6].

Fig. 2. Schematic view of the samples [Fe, Ni]/In. The conductance measurements were performed inside the working area $acdb$ enclosed by the dashed line.

Fig. 3. Upper panel: Temperature dependence of the Fe/In system resistance (curve 1) measured in the configuration shown in Inset a and that of the Fe part ac (curve 2) measured independently.

Inset a : Configuration of measurements. Thin lines schematically depict Fe conductors. Arrows indicate the current flow path.

Inset b : Indium bridge resistance vs temperature.

Lower panel: A section of curves 1, 2 in the vicinity of Indium superconducting transition on an enlarged scale.

Fig. 4. Resistance of the ferromagnetic Ni contour $acdb$ in wide (curve 1, Inset b) or point-like (curve 2, Inset c) contact with the superconducting In probes.

Fig. 5. Curve 1: Temperature-dependent resistance of the Indium bridge measured between the potential probes V_{11} , V_{12} beyond the F/S interface.

Curve 2: Temperature-dependent resistance of the Indium bridge in series with Ni/In interfaces measured between the probes V_{21} , V_{22} .

Inset: Configuration of measurements. Thin lines schematically depict Ni conductors. Arrows indicate the current flow path.

Fig. 6. Temperature dependence of the resistance at the interfaces Ni/In (curve 1) and Fe/In (curve 2). For details see text.











